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ATTORNEY DOCKET NO. 60188-413  
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
Gaku Sugahara, et al. )  
Serial No.: 09/890,095 ) Group Art Unit: 2828  
Filed: June 5, 2003 ) Examiner: J. KAHN  
For: SEMICONDUCTOR LASER DEVICE, METHOD FOR FABRICATING  
THE SAME, AND OPTICAL DISK APPARATUS )

AMENDMENT UNDER 37 C.F.R. § 1.111

Mail Stop Non-Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

RECEIVED  
JUN 18 2003  
TECHNOLOGY CENTER 2800

Sir:

In response to the Office Action dated February 14, 2003, having a shortened statutory period for response set to expire May 14, 2003, a petition for a one month extension of time up to and including June 14, 2003, please amend the above-identified application as follows:

IN THE SPECIFICATION:

Please amend the third full paragraph on page 21 to read as follows:

B' --In addition, a Group III-V nitride semiconductor, containing gallium nitride as a main component, is used a semiconductor material for the violet-light-emitting semiconductor laser device with an oscillation wavelength of about 400nm. Alternatively, any Group [II-IV] II-VI